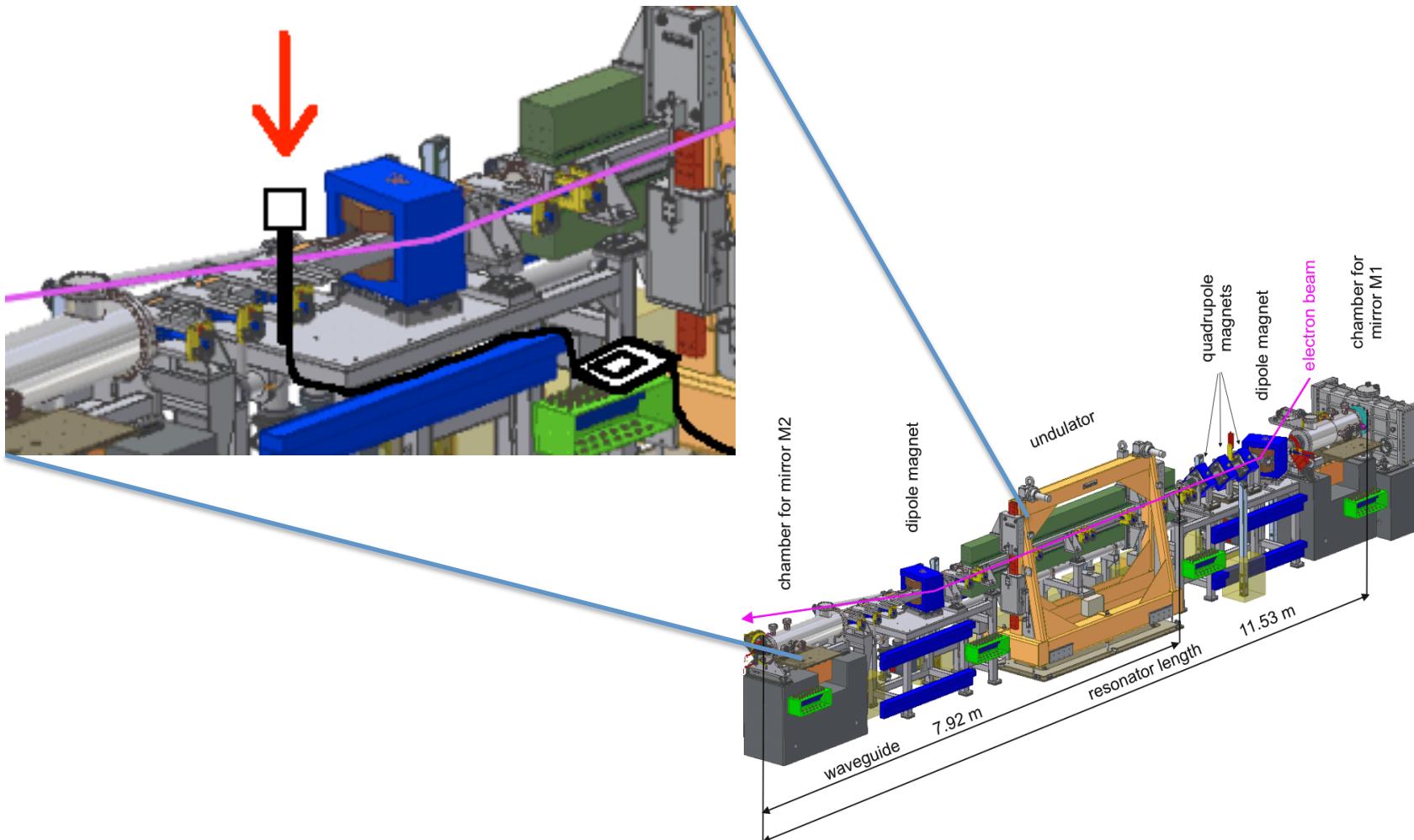


FEt Diode Diamond X-ray sensor

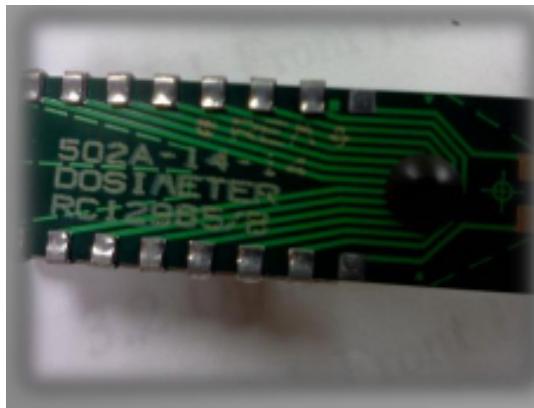
PHYS476 Final Presentation



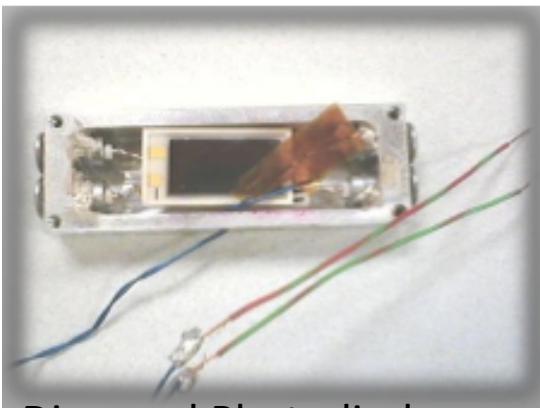
UHM KeitaF 5/8/2012

Background radiation sensors for FEL

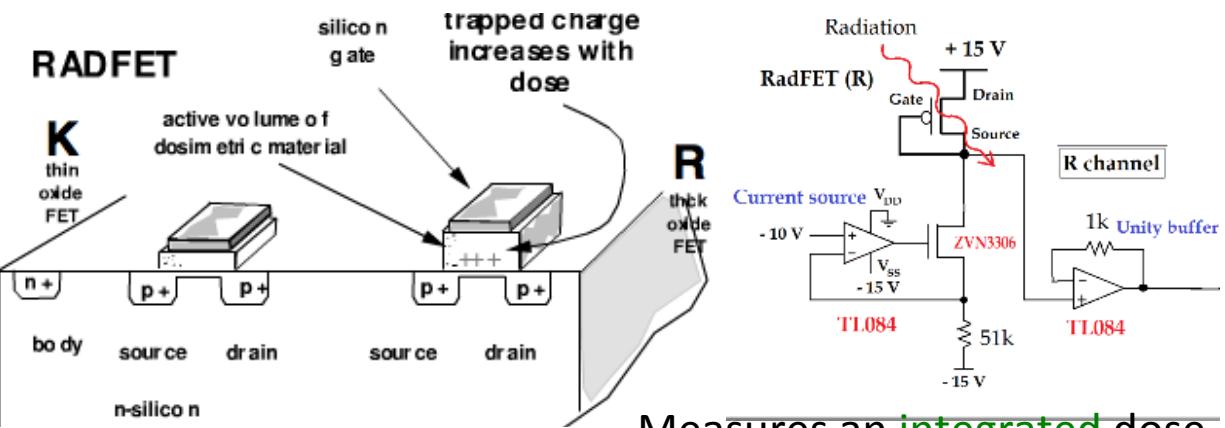
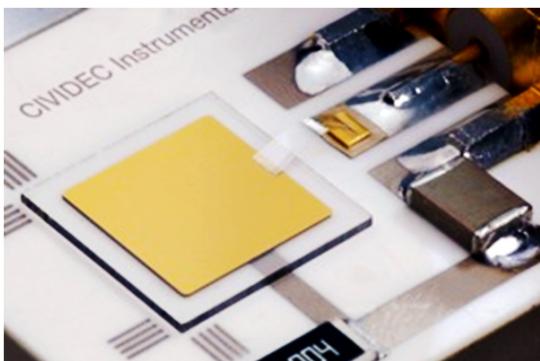
Radiation-sensing FETs



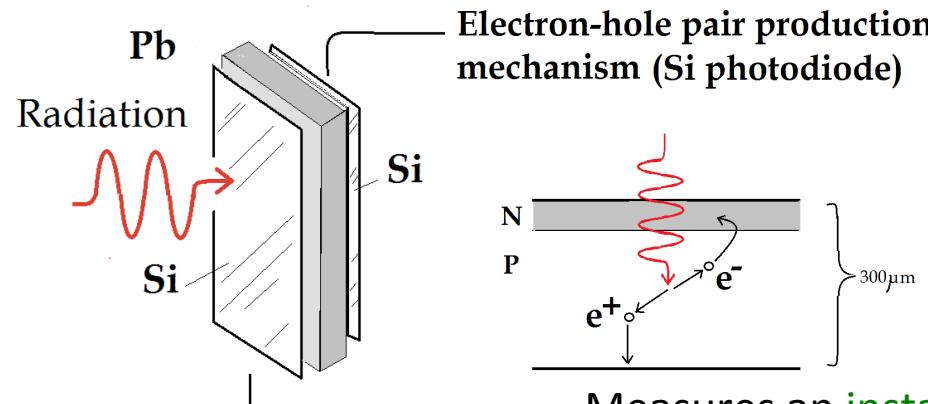
Silicon Photodiodes



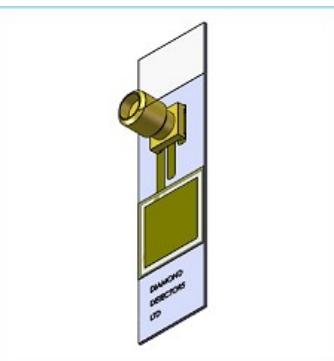
Diamond Photodiode



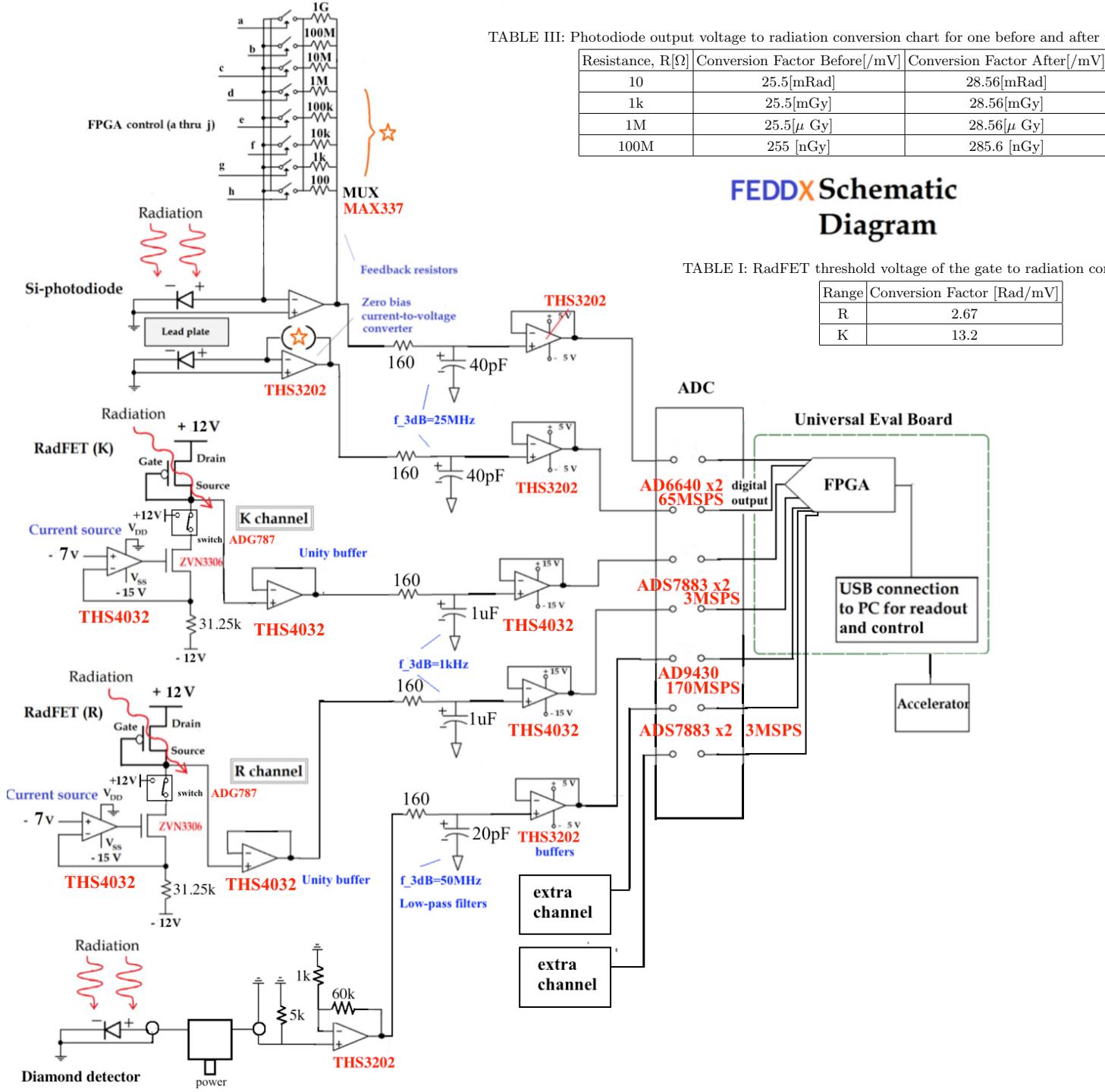
Measures an **integrated** dose



Measures an **instantaneous** dose



all in one.



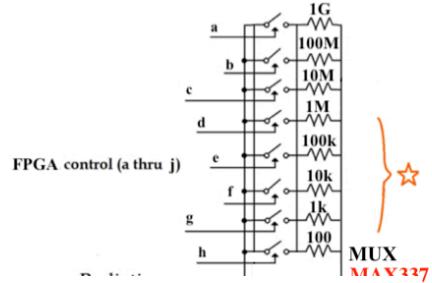
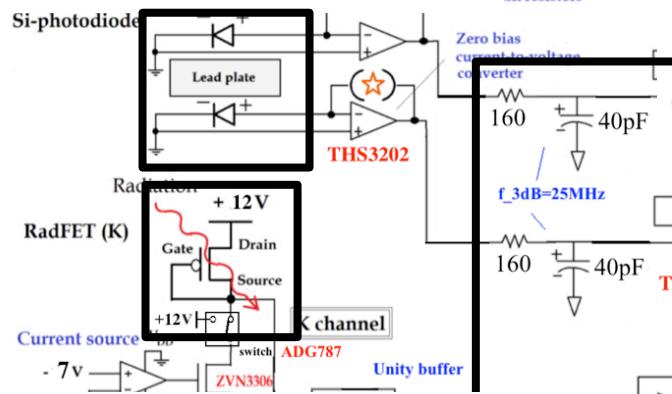


TABLE III: Photodiode output voltage to radiation conversion chart for one before and after the lead shield

Resistance, R [Ω]	Conversion Factor Before [mV]	Conversion Factor After [mV]
10	25.5[mRad]	28.56[mRad]
1k	25.5[mGy]	28.56[mGy]
1M	25.5[μ Gy]	28.56[μ Gy]
100M	255 [nGy]	285.6 [nGy]

Silicon Photodiodes



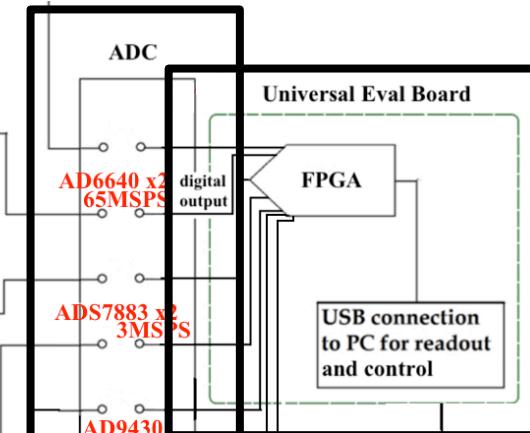
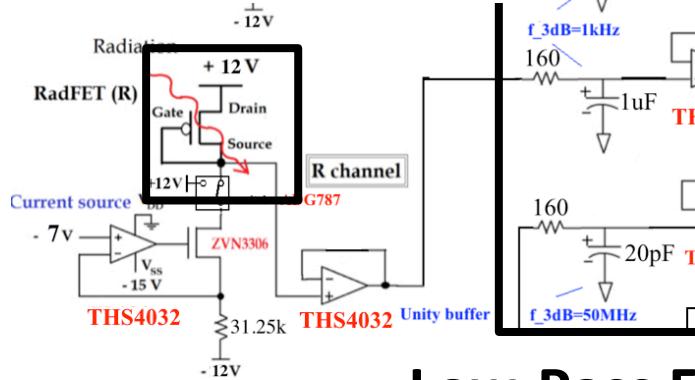
Analog to Digital Converter

FEDDX Schematic
Analog

voltage of the gate to radiation conversion chart.

conversion Factor [Rad/mV]
2.67
13.2

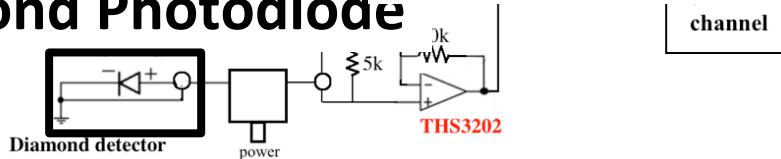
Radiation-sensing FETs



Digital to Computer Converter (Mother Board: Universal Eval. Board)

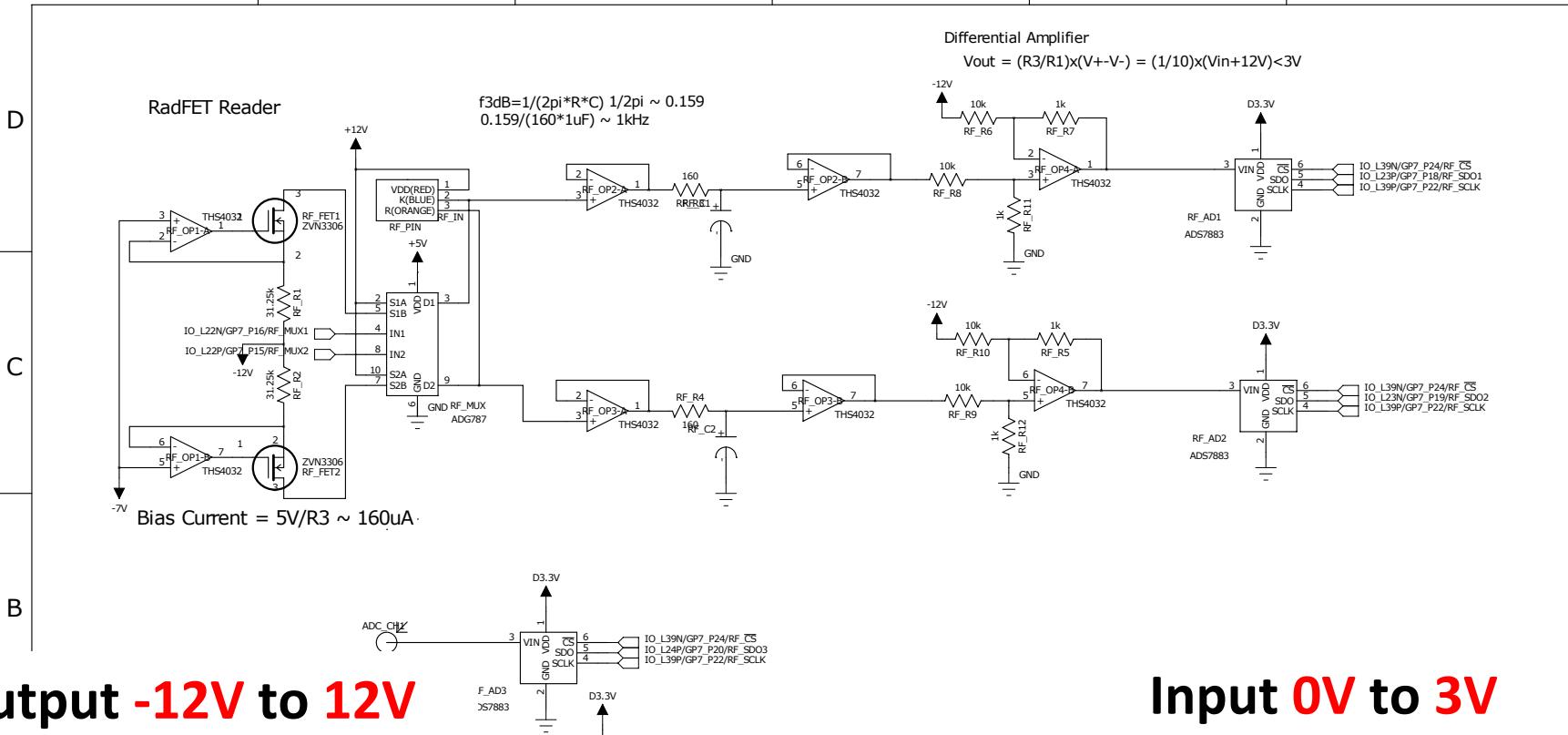
FEDDX Block Diagram

Diamond Photodiode



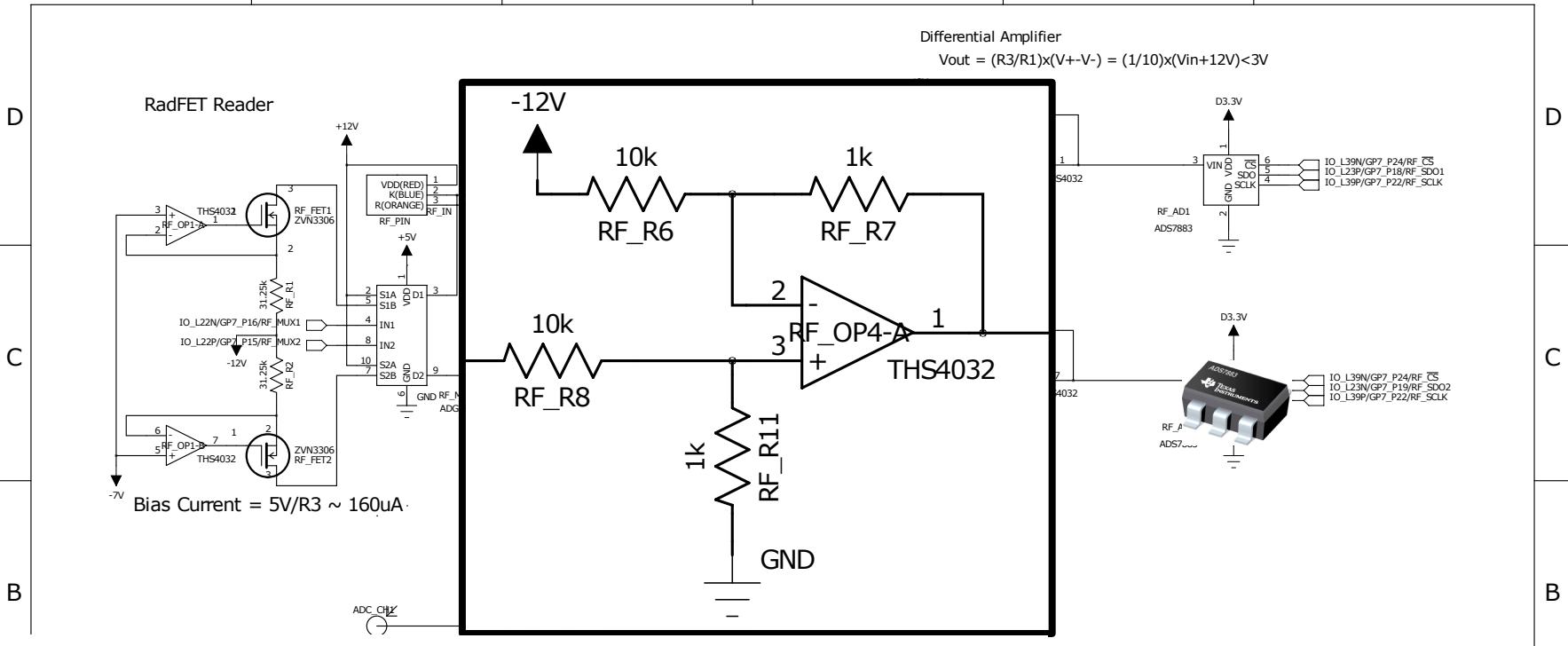
RadFET Schematic

6 | 5 | 4 | 3 | 2 | 1



RadFET Schematic

6 | 5 | 4 | 3 | 2 | 1



Output -12V to 12V

Differential Converter

Input 0V to 3V

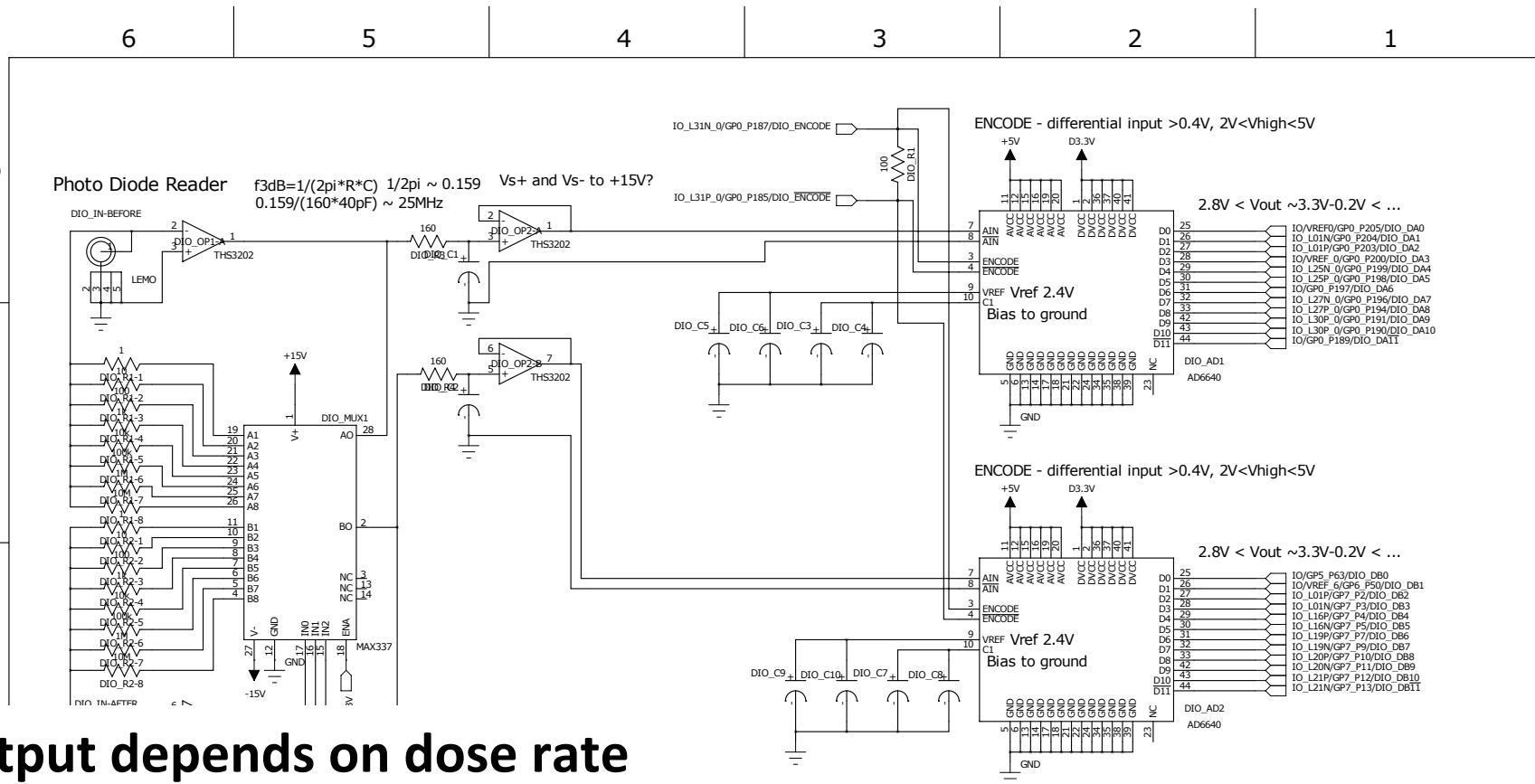


$$V_{out} = (R_3/R_1)(V_+ - V_-)$$

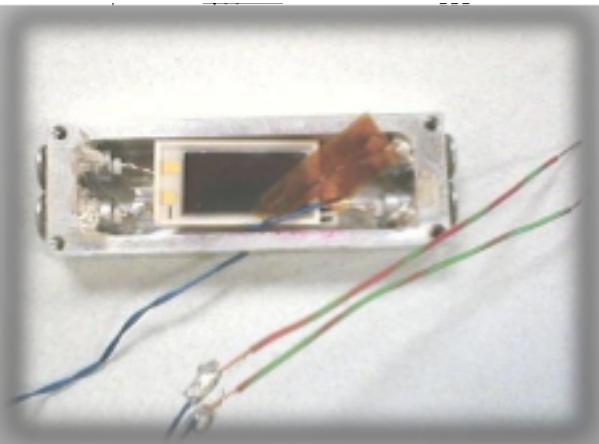
$$(1/10)(V_{in} - (-12V)) < 3V$$



Diode Schematic



Output depends on dose rate



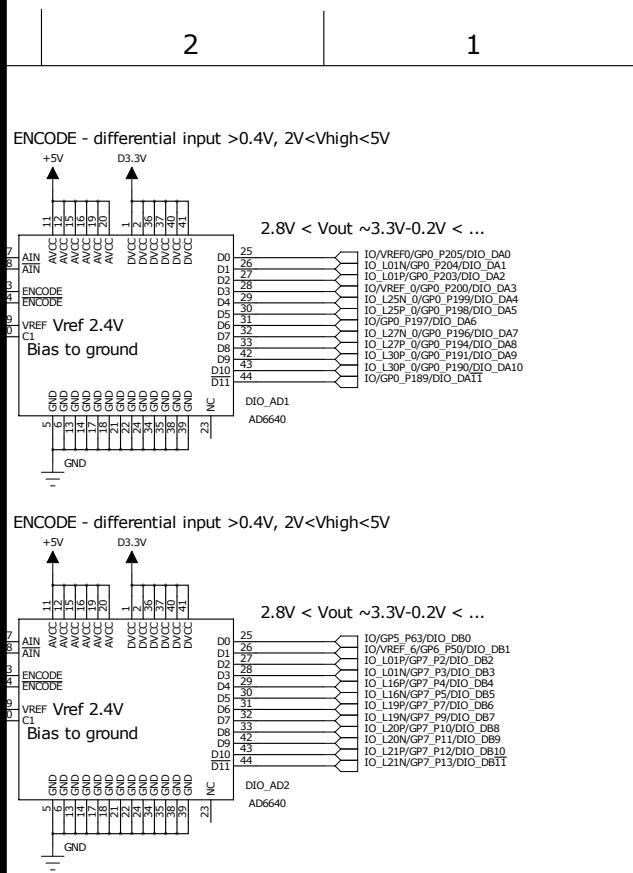
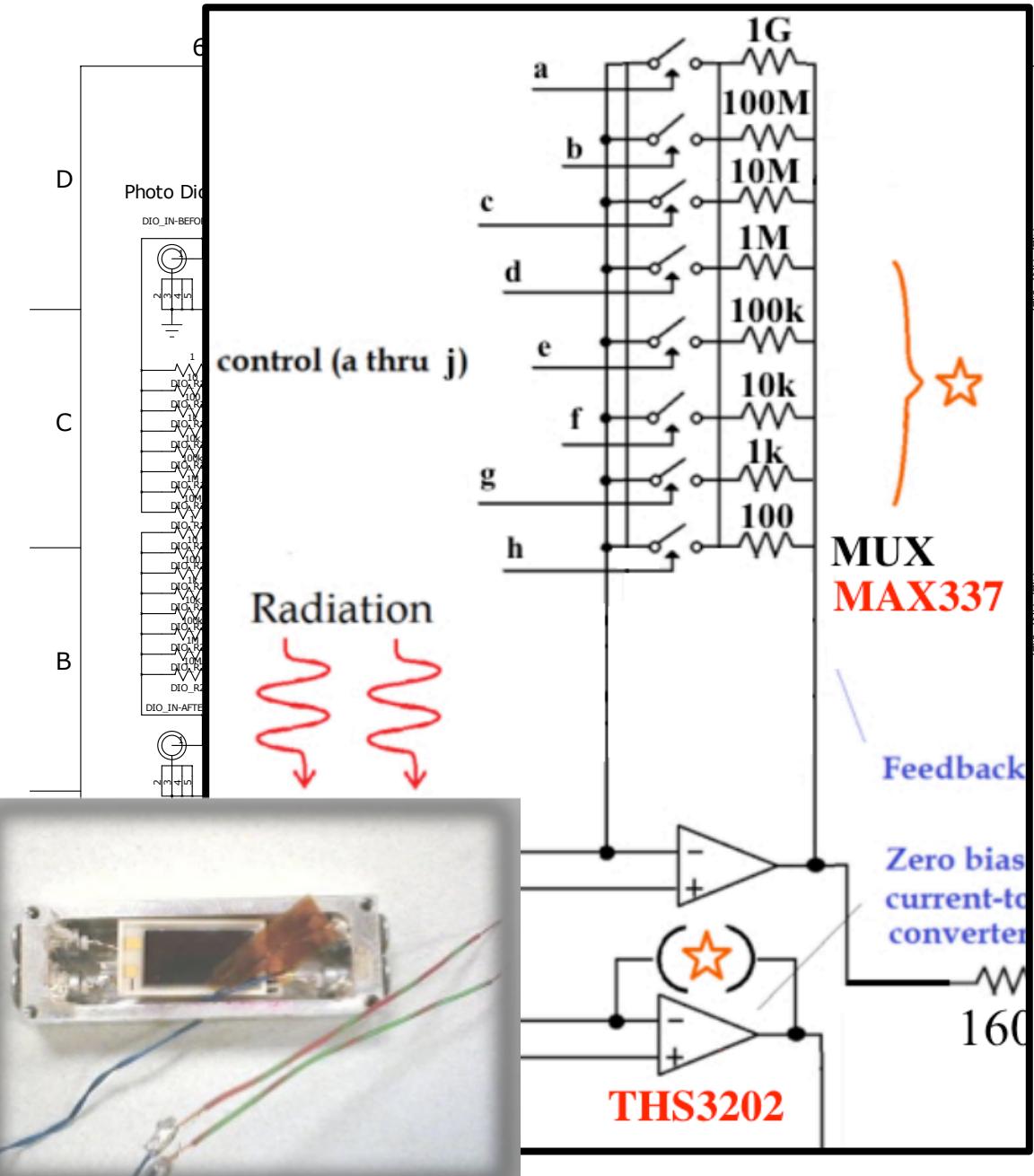
Univ. of Hawai'i -- PHYS476

TITLE: FEt, Diode, and Diamond X-ray sensor (FEDDX)

	Design: KF	Page Description: Photo Diode Reader	REV: A
DATED: 4-APR-12	[DIODE]	SHEET: 2 OF 5	

Current to Voltage Converter

Diode Schematic



$$V = R \frac{E_X}{E_{PE}} e_f$$

Diamond Schematic

6

5

4

3

7

1

D

C

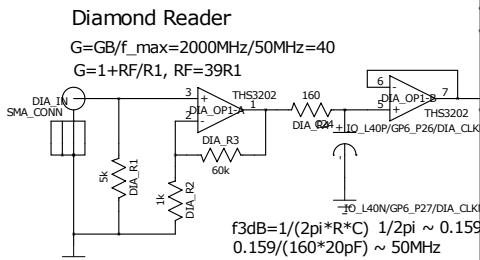
B

□

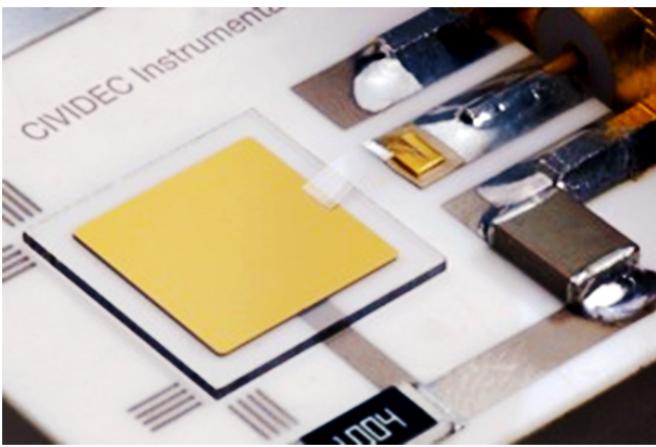
6

6

S1 - Data Format Select. GND = binary, AVDD = twos complement.
S2 - Output Mode Select. AVDD = LVDS.
S4 - Tie low when operating in LVDS
S5 - AVDD sets $f_S = 0.768$ V p-p differential, GND sets $f_S = 1.536$ V p-p differential.



120V bias recommended



Univ. of Hawai'i -- PHYS476

TITLE: FEt, Diode, and Diamond X-ray sensor (FEDDX)

Diamond Detector Reader

DATED: 4-APR-12 [DIAMOND] SHEET: 3 OF

Diamond Schematic

6

5

4

3

- 1 -

D

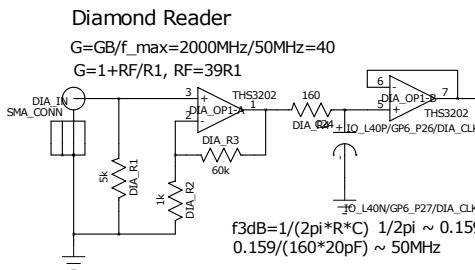
D

C

C

B

A

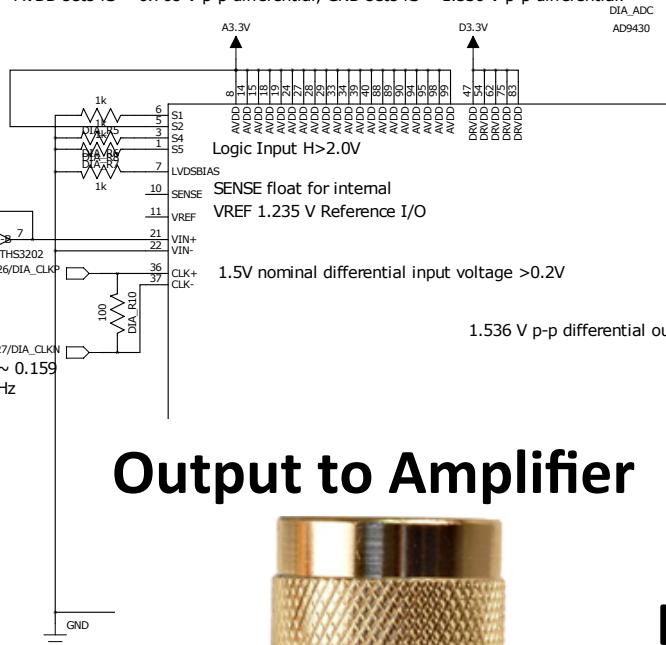


S1 - Data Format Select. GND = binary, AVDD = twos complement.

S2 - Output Mode Select. AVDD = LVDS.

S4 - Tie low when operating in LVDS

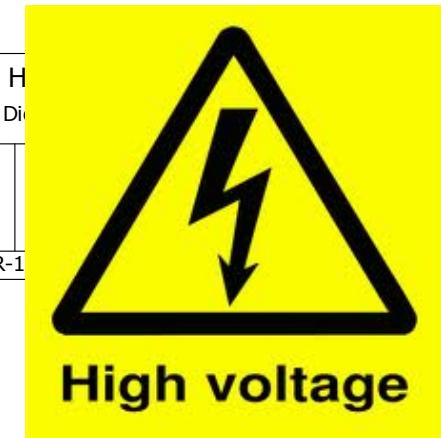
S5 - AVDD sets fS = 0.768 V p-p differential, GND sets fS = 1.536 V p-p differential.



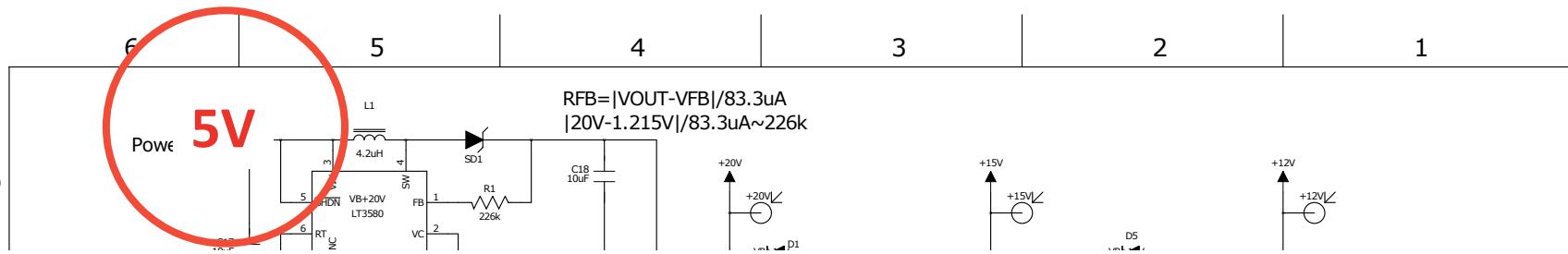
Output to Amplifier



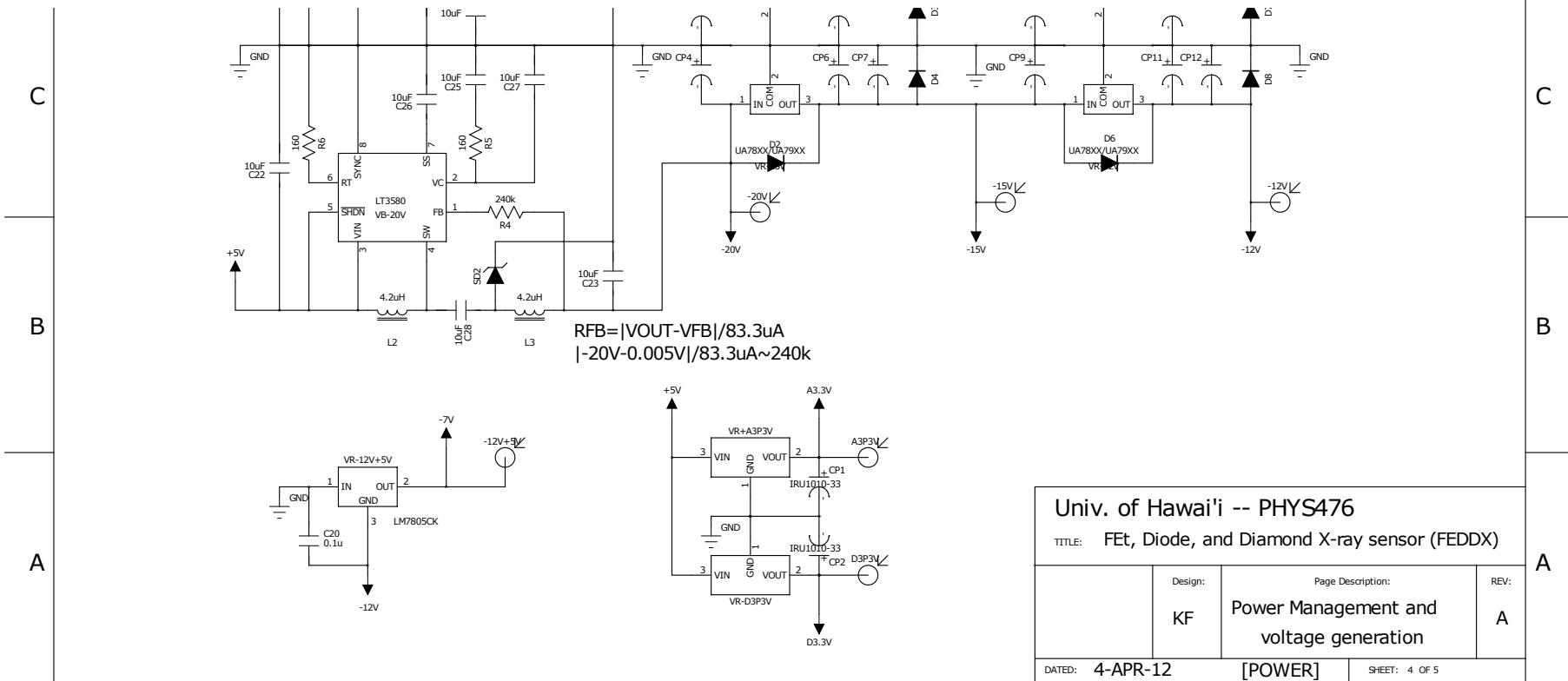
External 120V



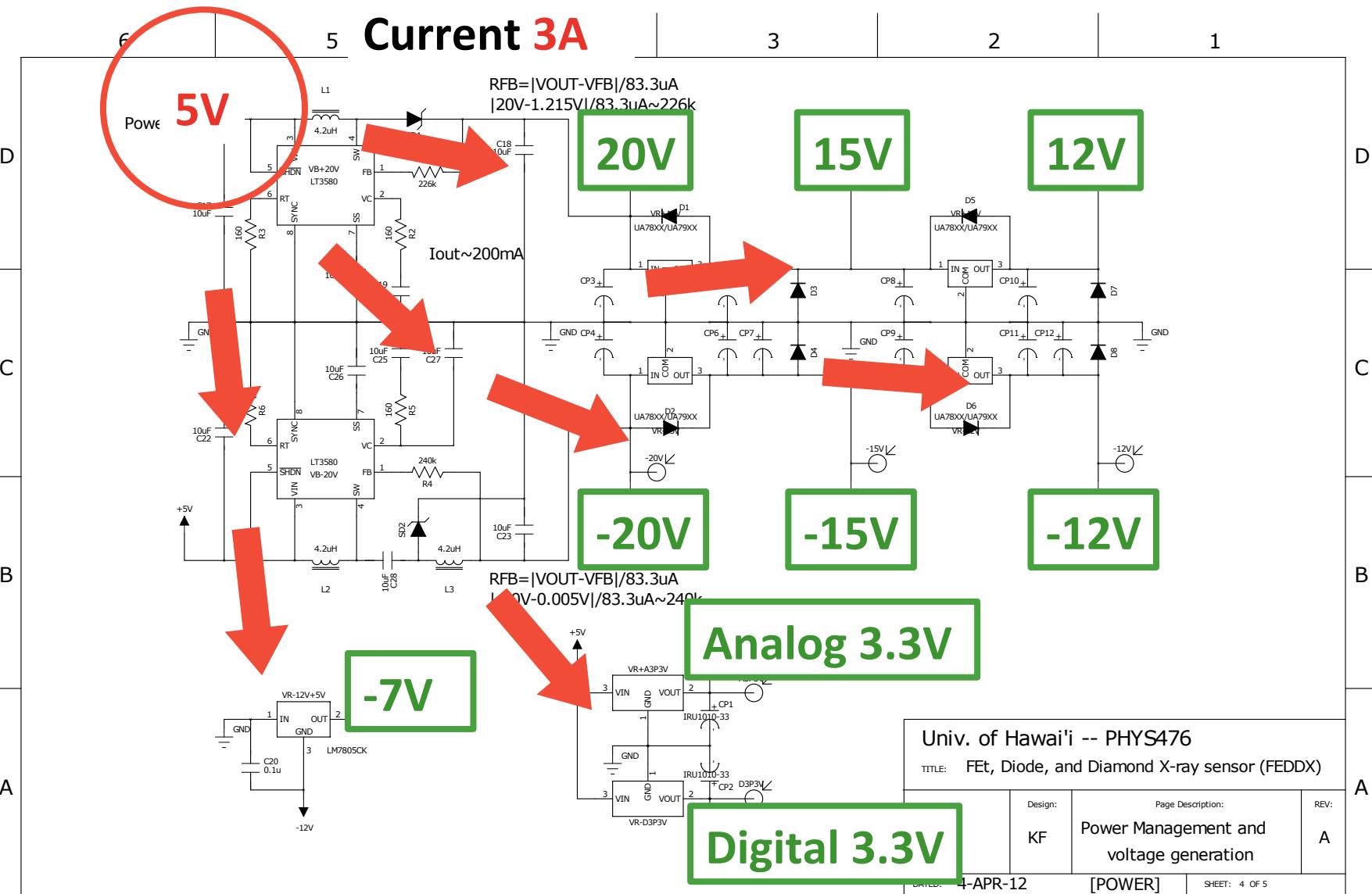
Power Schematic



Only 5V power supplied from the mother board (Univ. Eval.)



Power Schematic



Radiation-sensing FETs

R
K

Silicon Photodiodes

Analog 3.3V

Digital 3.3V

FEDDX Layout

Diamond Photodiode

12V

15V

20V

-12V

-15V

-20V

5V

-7V

5V

5V

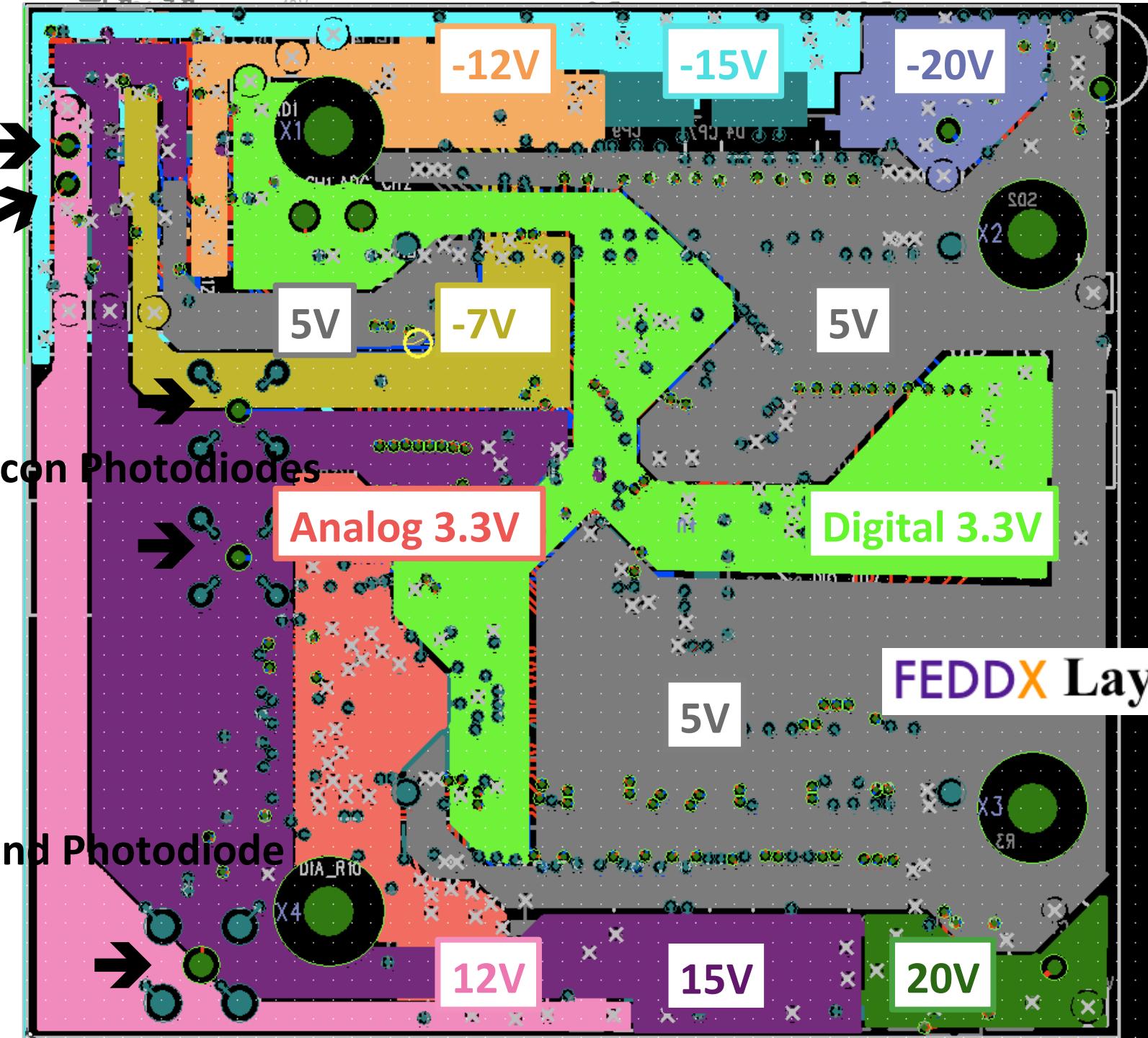
X1

X2

X3

DIA_R10

X4



Radiation-sensing FETs

R
K

Silicon Photodiodes

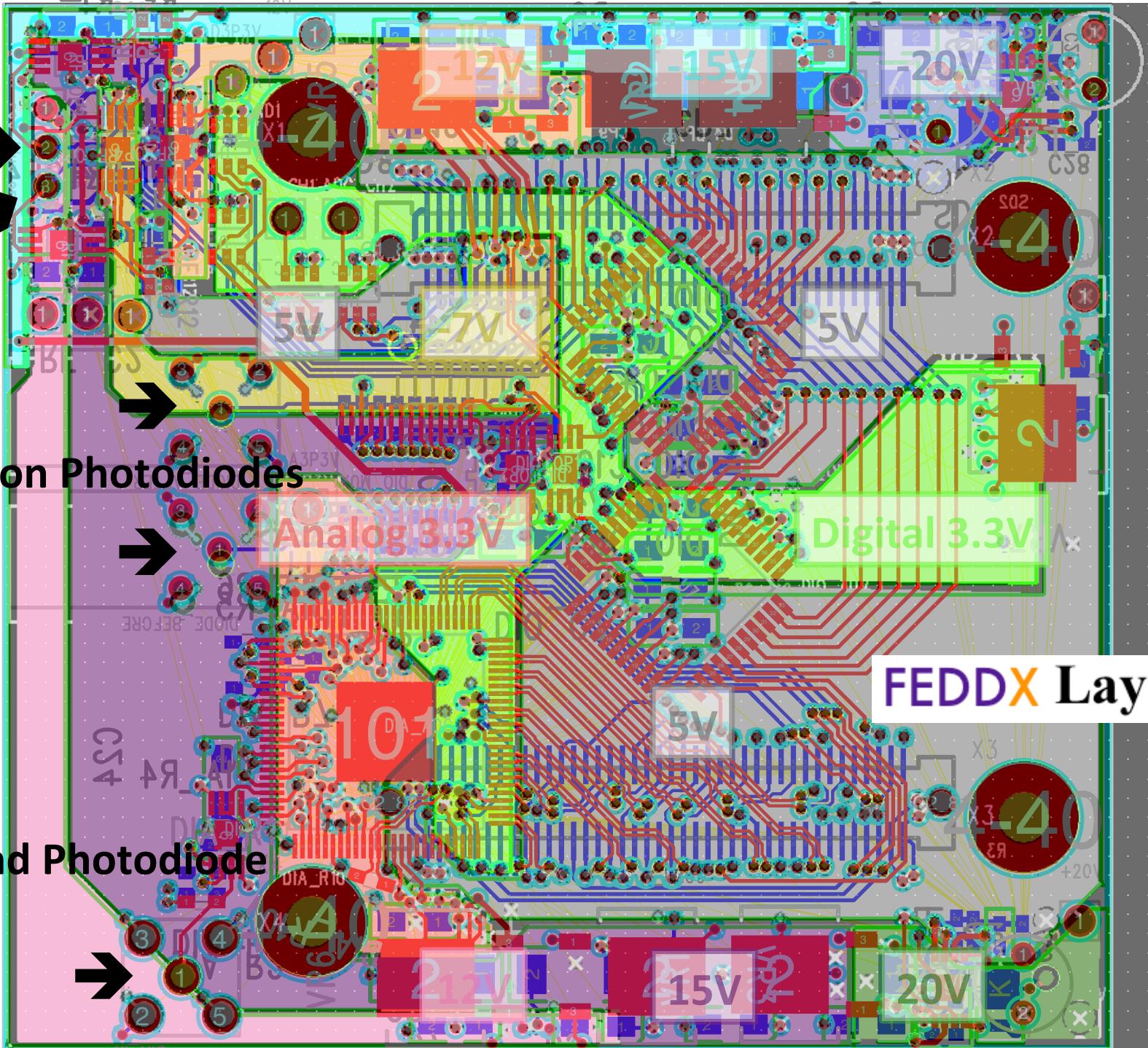


Analog 3.3V

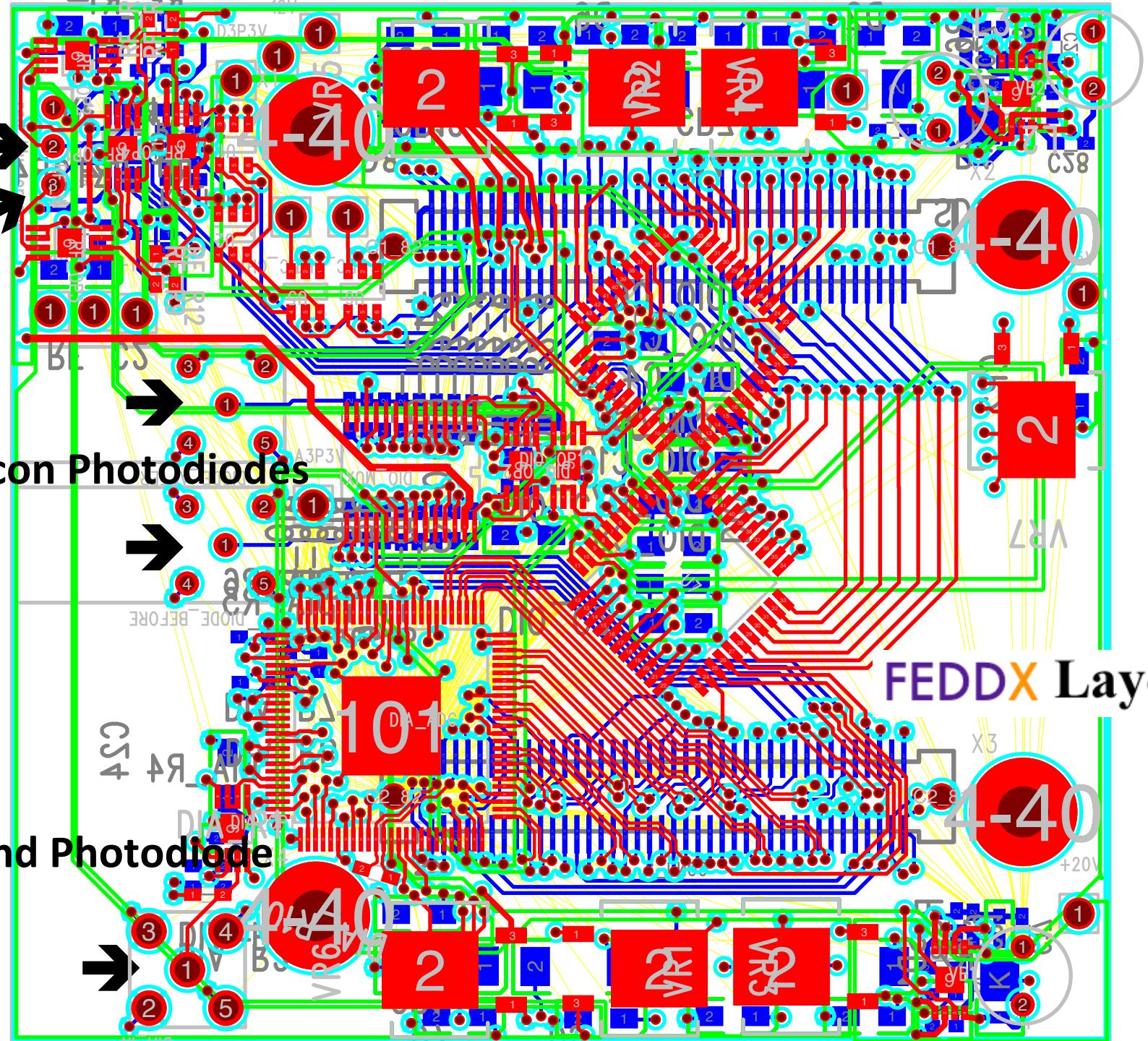
Digital 3.3V

FEDDX Layout

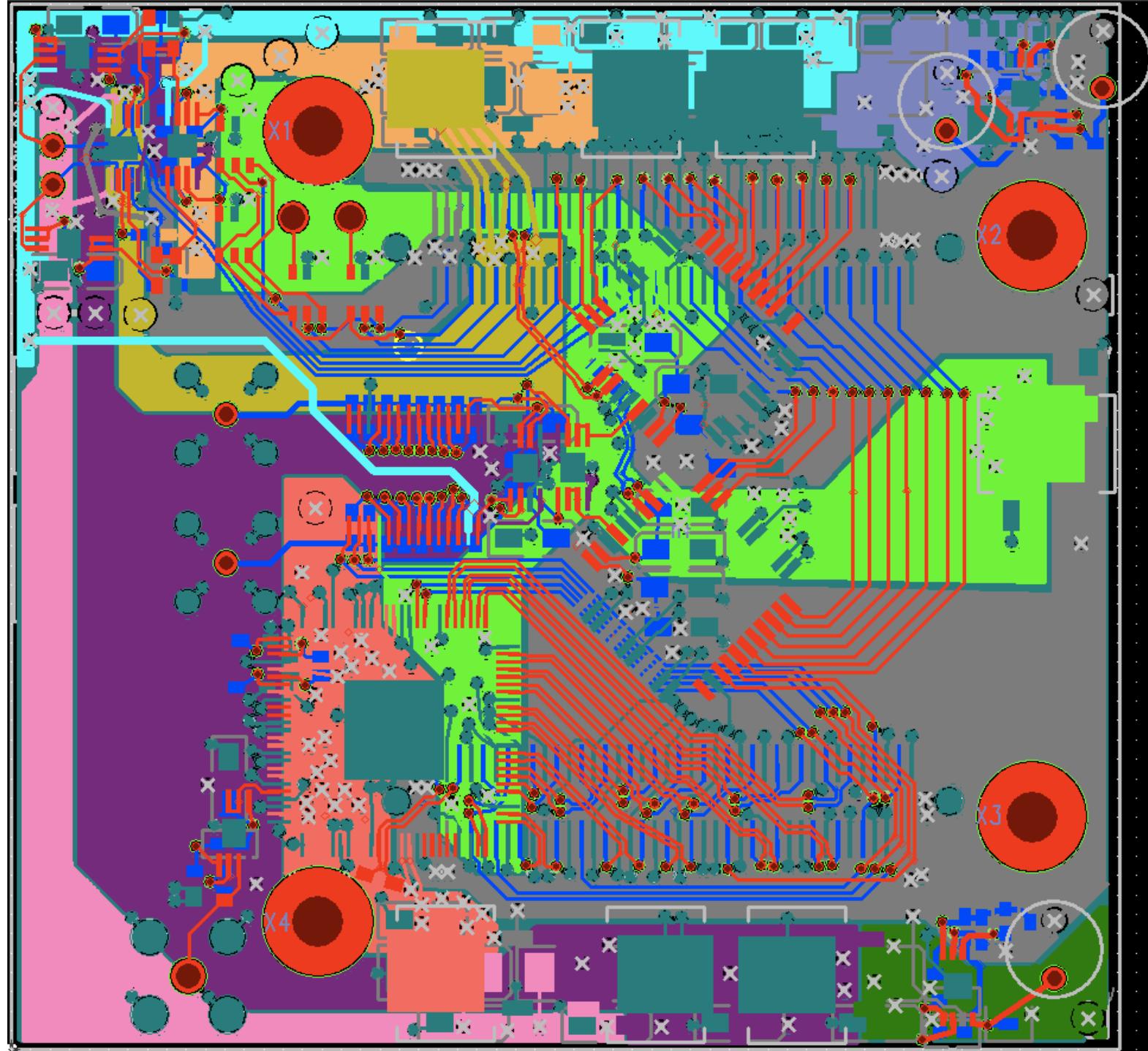
Diamond Photodiode

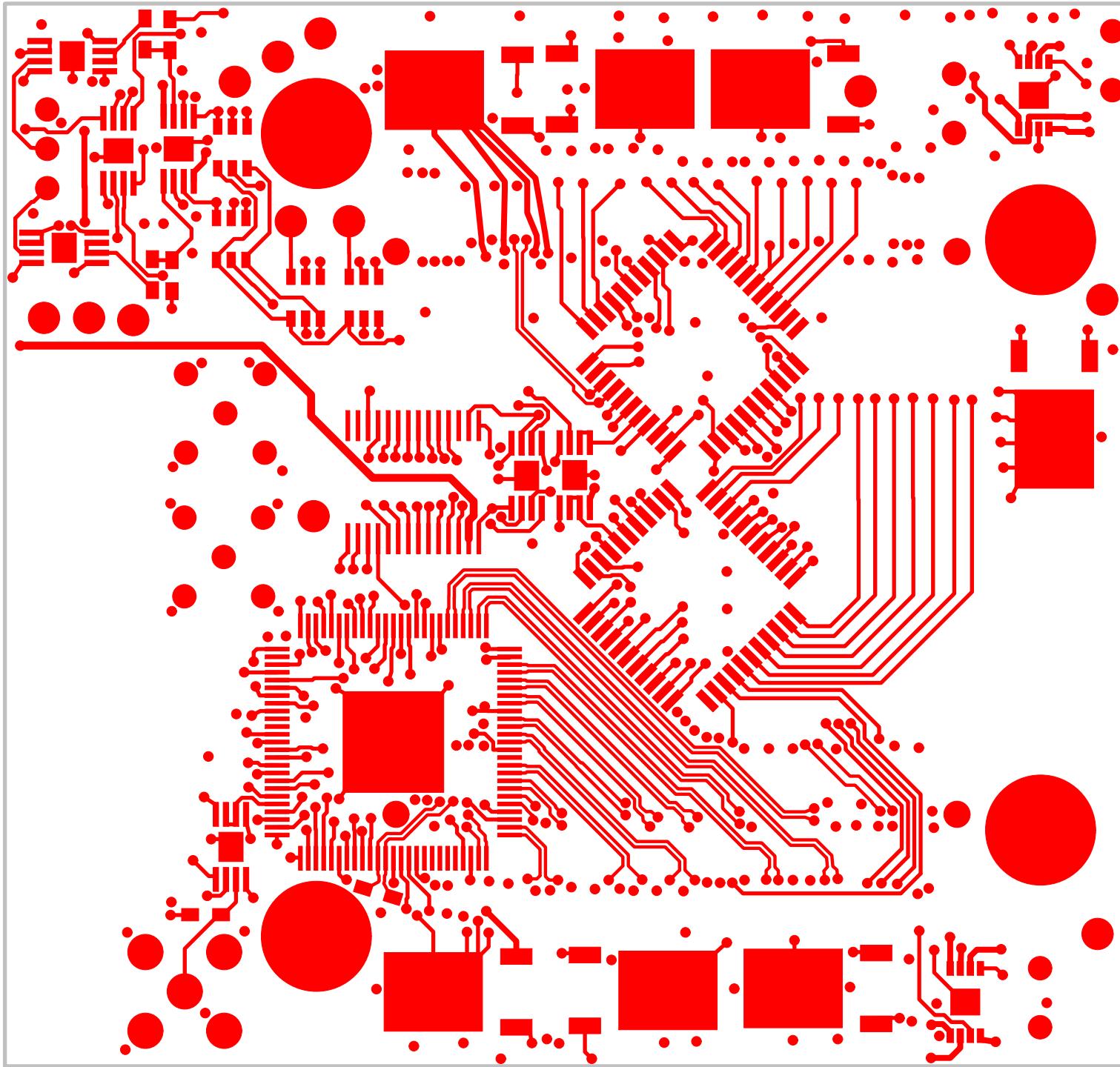


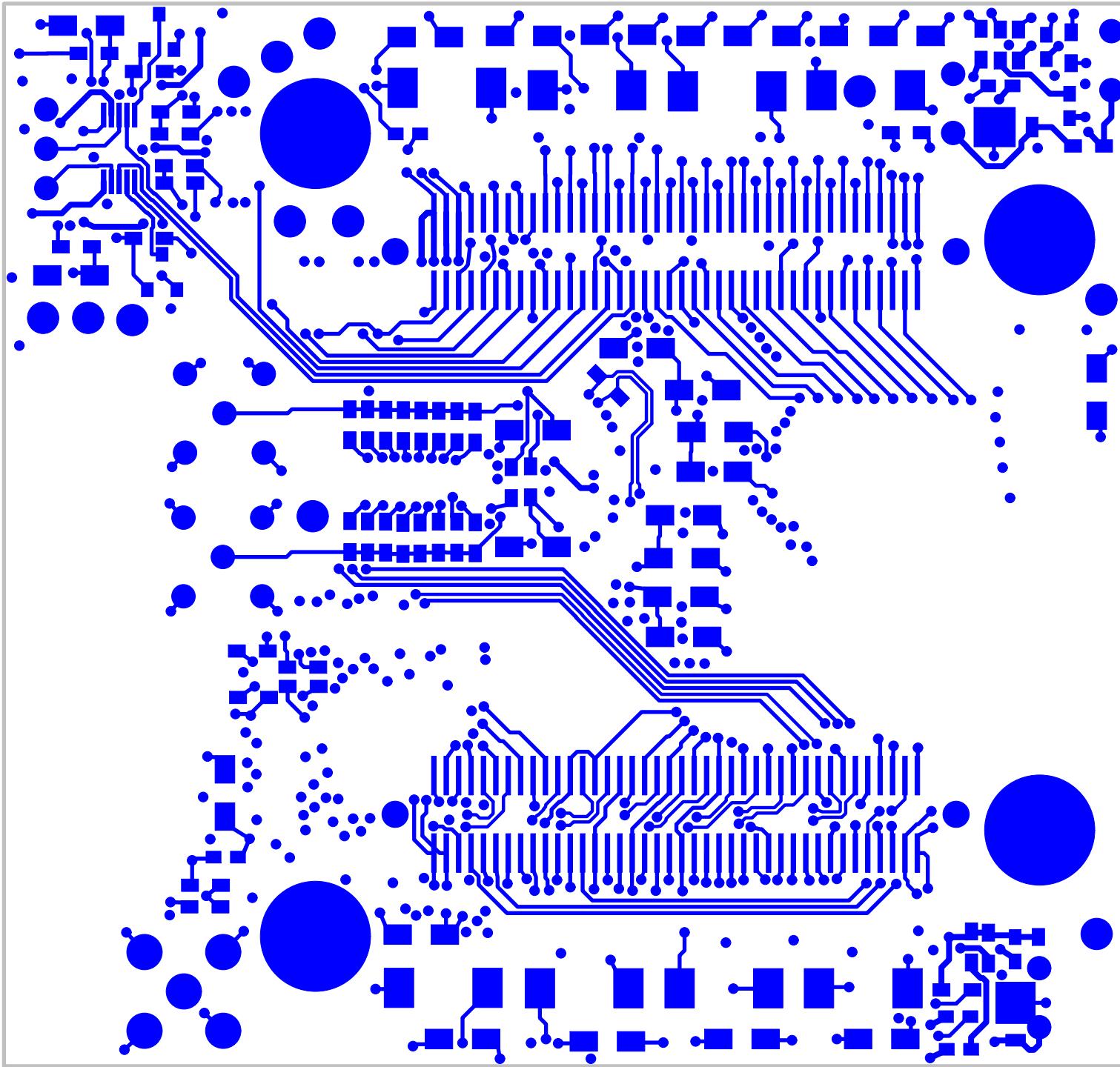
Radiation-sensing FETs



EXTRA SLIDES







6

5

4

3

2

1

E

D

C

B

A

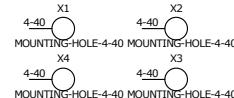
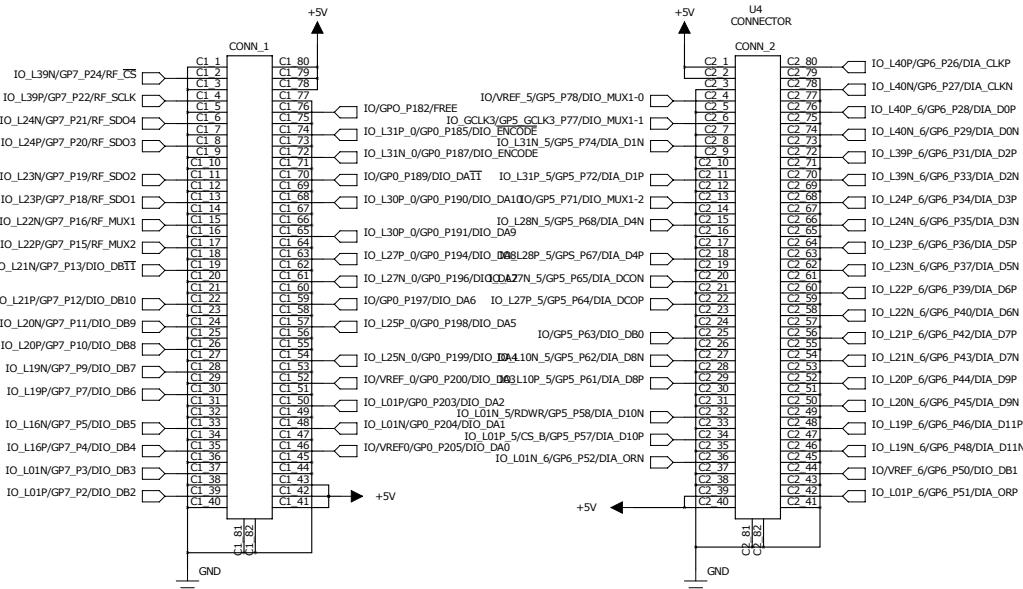
E

D

C

B

A



institution:	University of Hawaii at Manoa High Energy Physics Lab Instrumentation Development Lab
title:	TARGET4 Daughtercard
revision:	A
IDLAB design #:	IDL_12_004
circuit design:	GSV
PCB design:	DMD
sheet #:	2 of 2
sheet description:	TARGET3 input/output
date last modified:	February 14, 2012